

TRENCHSTOP™ Series

Low Loss IGBT: IGBT in TRENCHSTOP™ and Fieldstop technology









Features:

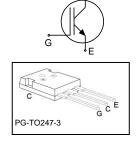
- Very low V_{CE(sat)} 1.5V (typ.)
- Maximum Junction Temperature 175°C
- Short circuit withstand time $5\mu s$
- Designed for : •
 - Frequency Converters
 - Uninterrupted Power Supply
- TRENCHSTOP™ and Fieldstop technology for 600V applications offers : very tight parameter distribution high ruggedness, temperature stable behavior
 - - very high switching speed
- Positive temperature coefficient in V_{CE(sat)} .
- Low EMI
- Low Gate Charge .
- Qualified according to JEDEC¹ for target applications •
- Pb-free lead plating; RoHS compliant ٠
- Complete product spectrum and PSpice Models : http://www.infineon.com/igbt/

Туре	V _{CE}	I _C	V _{CE(sat),Tj=25℃}	T _{j,max}	Marking	Package
IGW75N60T	600V	75A	1.5V	175°C	G75T60	PG-TO247-3

Maximum Ratings

Parameter	Symbol	Value	Unit
Collector-emitter voltage, $T_j \ge 25^{\circ}C$	V _{CE}	600	V
DC collector current, limited by T_{jmax}			
$T_{\rm C} = 25^{\circ}{\rm C}$	I _C	118	
$T_{\rm C} = 100^{\circ}{\rm C}$		85	A
Pulsed collector current, t_p limited by T_{jmax}	<i>I</i> _{Cpuls}	225	
Turn off safe operating area $V_{CE} = 600V$, $T_j = 175^{\circ}C$, $t_p = 1\mu s$	-	225	
Gate-emitter voltage	V _{GE}	±20	V
Short circuit withstand time ²⁾	4	F	
V_{GE} = 15V, $V_{\text{CC}} \le 400$ V, $T_j \le 150^\circ$ C	t _{sc}	5	μS
Power dissipation $T_{\rm C} = 25^{\circ}{\rm C}$	P _{tot}	428	W
Operating junction temperature	Tj	-40+175	
Storage temperature	$T_{\rm stg}$	-55+150	°C
Soldering temperature, 1.6mm (0.063 in.) from case for 10s	-	260	

 1 J-STD-020 and JESD-022 $^{2)}$ Allowed number of short circuits: <1000; time between short circuits: <1s.





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Thermal Resistance

Parameter	Symbol	Conditions	Max. Value	Unit
Characteristic				
IGBT thermal resistance,	R _{thJC}		0.35	K/W
junction – case				
Thermal resistance,	R _{thJA}		40	
junction – ambient				

Electrical Characteristic, at T_j = 25 °C, unless otherwise specified

Parameter	Sumbol	Conditions	Value			Unit
Farameter	Symbol	Conditions	min.	Тур.	max.	Unit
Static Characteristic						
Collector-emitter breakdown voltage	V _{(BR)CES}	$V_{GE}=0V, I_{C}=0.2mA$	600	-	-	V
Collector-emitter saturation voltage	V _{CE(sat)}	$V_{\rm GE} = 15 V, I_{\rm C} = 75 A$				
		T _j =25°C	-	1.5	2.0	
		<i>T</i> _j =175°C	-	1.9	-	
Gate-emitter threshold voltage	V _{GE(th)}	$I_{\rm C}=1.2$ mA, $V_{\rm CE}=V_{\rm GE}$	4.1	4.9	5.7	
Zero gate voltage collector current	I _{CES}	V _{CE} =600V, V _{GE} =0V				μA
		T _j =25°C	-	-	40	
		<i>T</i> _j =175°C	-	-	5000	
Gate-emitter leakage current	I _{GES}	$V_{\rm CE} = 0 \text{V}, V_{\rm GE} = 20 \text{V}$	-	-	100	nA
Transconductance	$g_{ m fs}$	$V_{\rm CE} = 20 V, I_{\rm C} = 75 A$	-	41	-	S
Integrated gate resistor	R _{Gint}			-		Ω

Dynamic Characteristic

Input capacitance	Ciss	V _{CE} =25V,	-	4620	-	pF
Output capacitance	Coss	$V_{GE}=0V$,	-	288	-	
Reverse transfer capacitance	Crss	f=1MHz	-	137	-	
Gate charge	Q _{Gate}	$V_{\rm CC}$ =480V, $I_{\rm C}$ =75A	-	470	-	nC
		$V_{GE}=15V$				
Internal emitter inductance	LE		-	13	-	nH
measured 5mm (0.197 in.) from case						
Short circuit collector current ¹⁾	I _{C(SC)}	V_{GE} =15V, t_{SC} ≤5 μ s V_{CC} = 400V, T_j ≤ 150°C	-	687.5	-	A

¹⁾ Allowed number of short circuits: <1000; time between short circuits: >1s.



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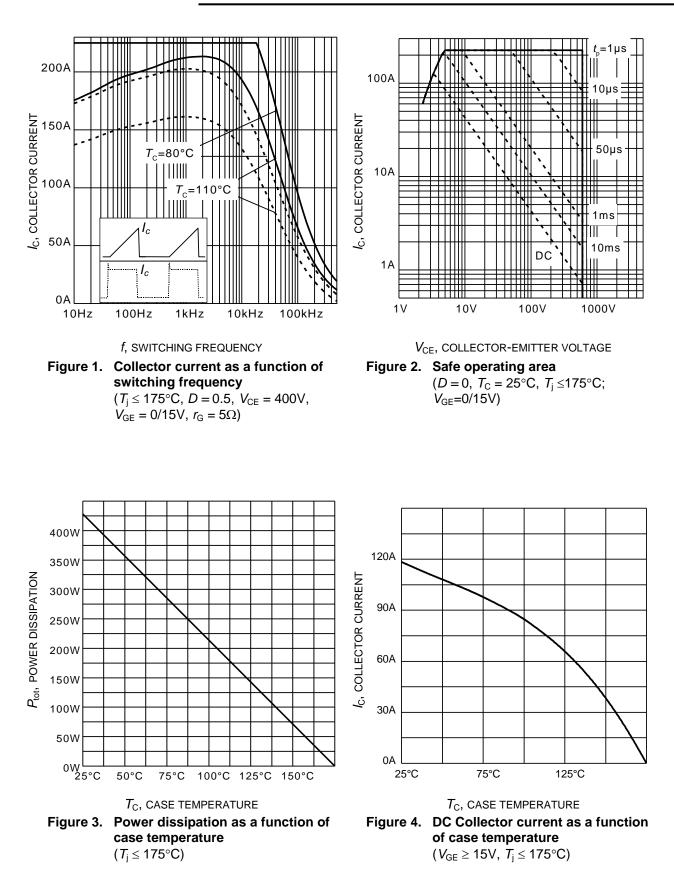
Switching Characteristic, Inductive Load, at $T_i=25$ °C

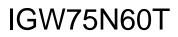
Parameter	Symbol C	O an dition a	Value			11
		Conditions	min.	Тур.	max.	Unit
IGBT Characteristic		·				
Turn-on delay time	t _{d(on)}	<i>T</i> _j =25°C,	-	33	-	ns
Rise time	t _r	V _{CC} =400V, <i>I</i> _C =75A, V _{GE} =0/15V,	-	36	-	
Turn-off delay time	$t_{d(off)}$	$r_{G}=5\Omega$, $L_{\sigma}=100$ nH, $C_{\sigma}=39$ pF L_{σ} , C_{σ} from Fig. E Energy losses include "tail" and diode reverse	-	330	-	
Fall time	t _f		-	35	-	
Turn-on energy ¹⁾	Eon		-	2.0	-	mJ
Turn-off energy	E _{off}		-	2.5	-	
Total switching energy	E _{ts}	recovery. Diode from IKW75N60T	-	4.5	-	

Switching Characteristic, Inductive Load, at T_j =175 °C

Parameter	Symbol	Conditions	Value			11
			min.	Тур.	max.	Unit
IGBT Characteristic		·				
Turn-on delay time	t _{d(on)}	<i>T</i> _j =175°C,	-	32	-	ns
Rise time	t _r	V _{CC} =400V, <i>I</i> _C =75A, V _{GE} =0/15V,	-	37	-	
Turn-off delay time	$t_{d(off)}$	$r_{\rm G}$ =5 Ω , L_{σ} =100nH, C_{σ} =39pF L_{σ} , C_{σ} from Fig. E Energy losses include "tail" and diode reverse	-	363	-	
Fall time	tf		-	38	-	
Turn-on energy ¹⁾	Eon		-	2.9	-	mJ
Turn-off energy	E _{off}		-	2.9	-	
Total switching energy	E _{ts}	recovery. Diode from IKW75N60T	-	5.8	-	

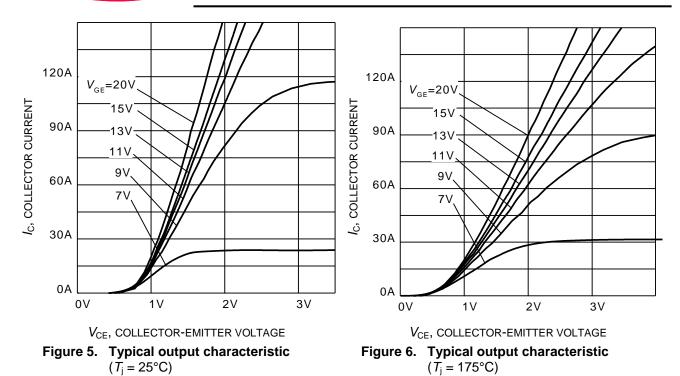


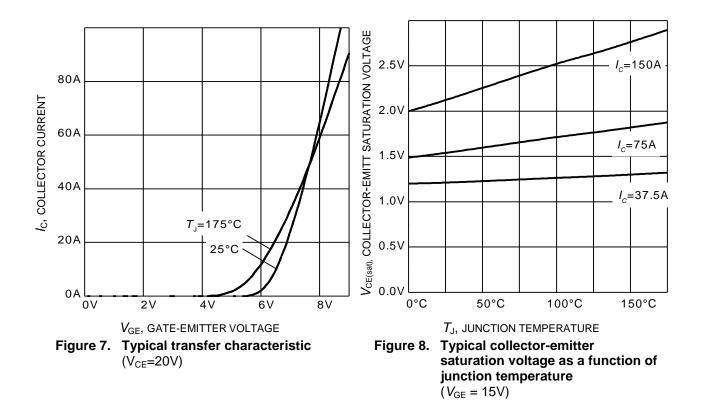




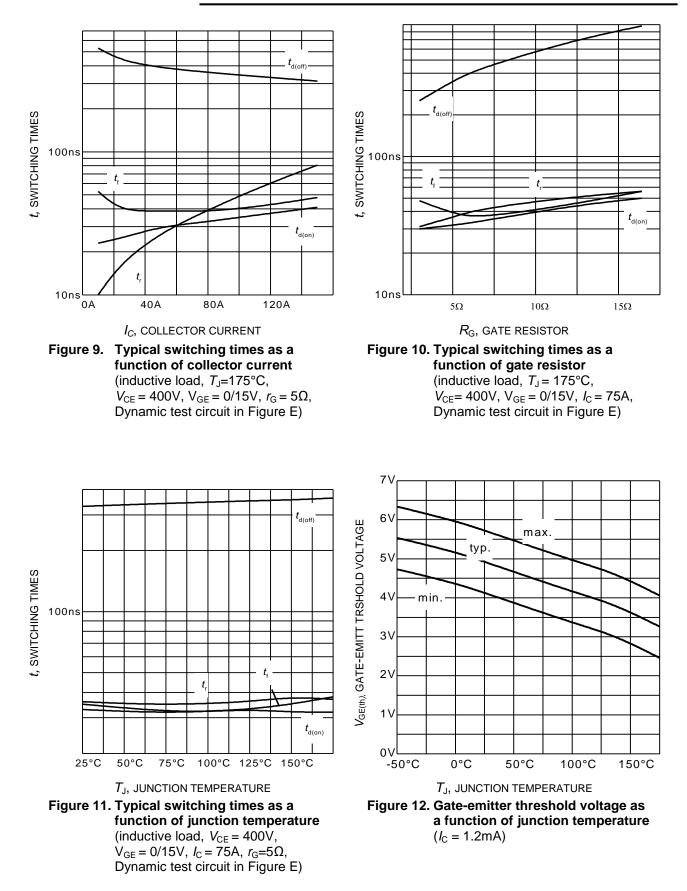


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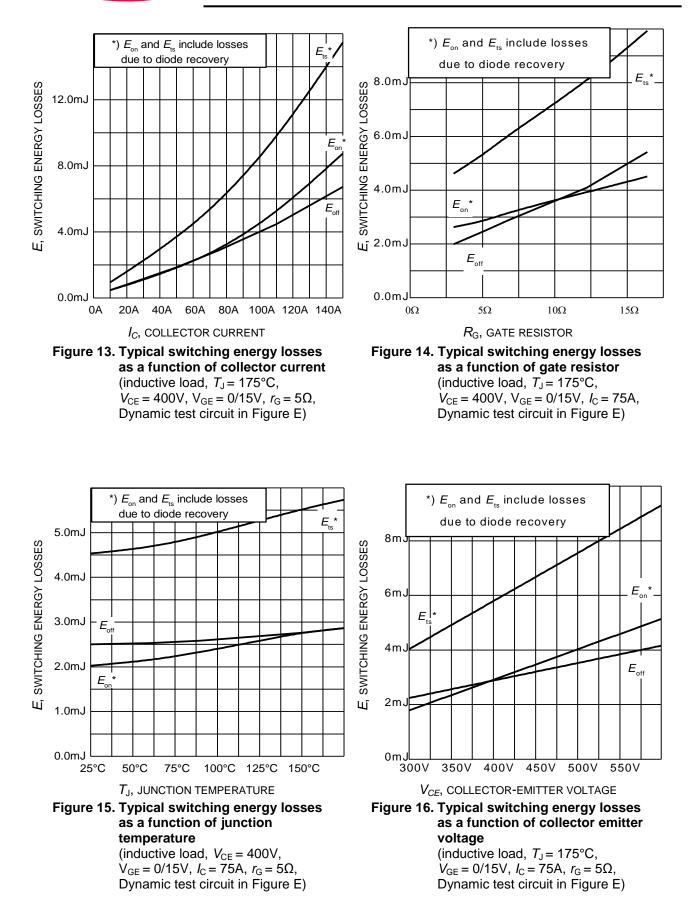














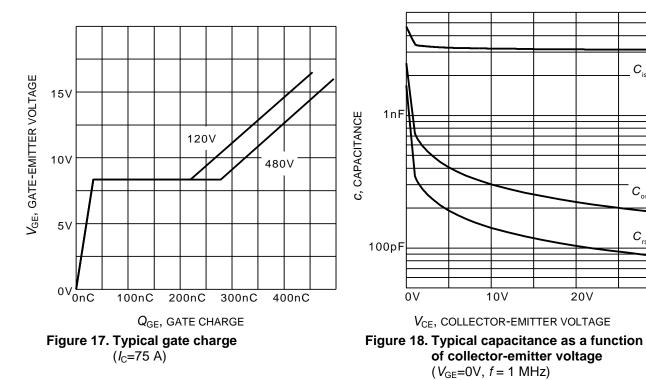
 $\boldsymbol{C}_{\text{iss}}$

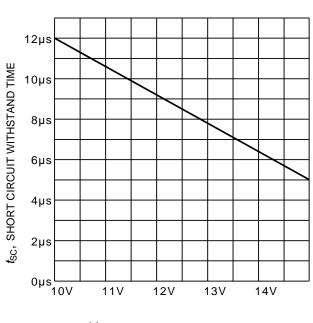
 $C_{\rm oss}$

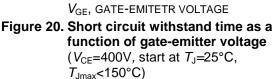
C

20V

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 $I_{\rm C(sc)}$, short circuit collector current

1000A

750A

500A

250A

0A 12V

14V

16V

 V_{GE} , GATE-EMITTETR VOLTAGE

 $(V_{CE} \le 400 \text{V}, T_{i} \le 150^{\circ}\text{C})$

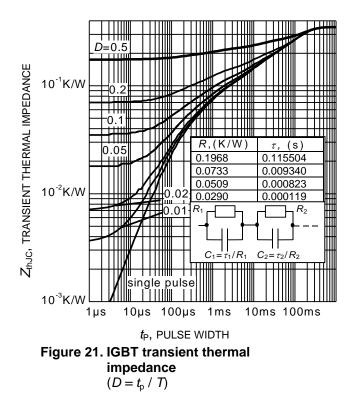
current as a function of gate-

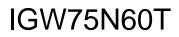
Figure 19. Typical short circuit collector

emitter voltage

18V







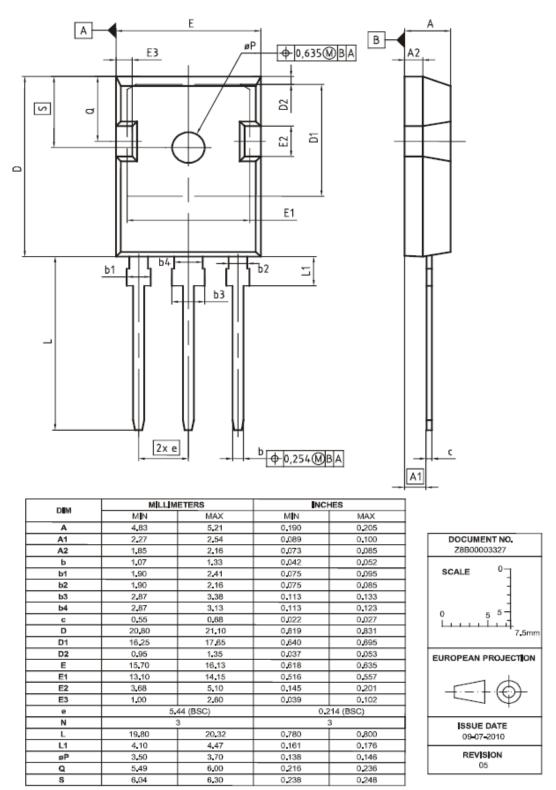
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TRENCHSTOP[™] Series

PG-TO247-3





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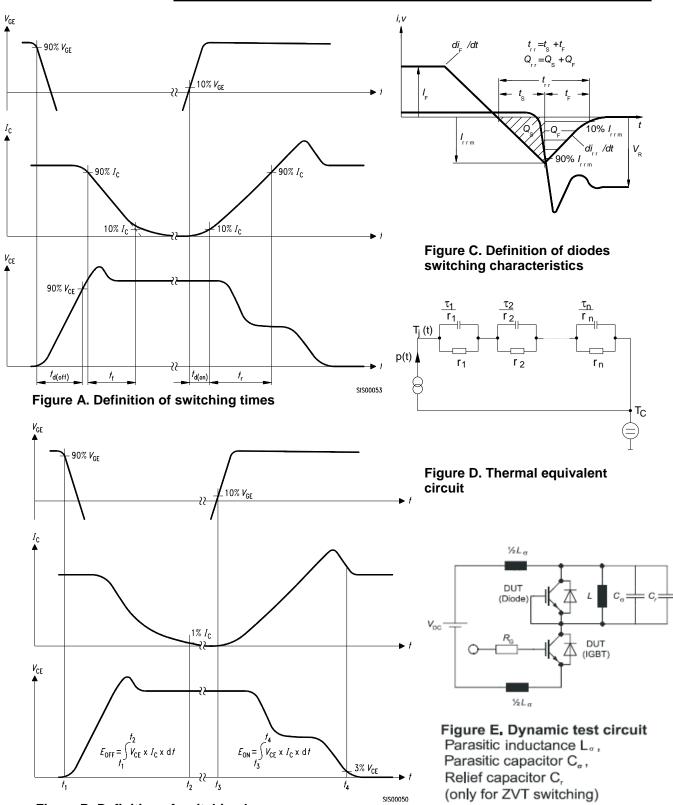


Figure B. Definition of switching losses



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